

CBCS SCHEME

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17ELN15/25

First/Second Semester B.E. Degree Examination, Dec.2023/Jan.2024 Basic Electronics

Time: 3 hrs.

Max. Marks: 100

Note: Answer any FIVE full questions, choosing ONE full question from each module.

Module-1

- 1 a. Draw and explain the V-I characteristics for silicon and germanium diode. (08 Marks)
b. Define the following diode parameters :
i) Knee voltage
ii) Minimum forward current
iii) Reverse breakdown voltage
iv) Peak inverse voltage. (08 Marks)
c. Derive the relationship between α and β . A certain transistor has $\beta = 200$ and base current is $50\mu\text{A}$. Determine the collector current and α . (04 Marks)

OR

- 2 a. With a neat diagram, explain the input and output characteristics of a transistor in common emitter configurations. (08 Marks)
b. With neat circuit diagram and waveform, explain the working of full wave bridge rectifier. (08 Marks)
c. Explain Zener diode voltage regulator circuit. (04 Marks)

Module-2

- 3 a. What is DC load line? Explain with neat circuit the operation of voltage divider bias circuit. (08 Marks)
b. Explain the characteristics of an ideal op-amp in detail. (08 Marks)
c. Explain the base bias circuit. (04 Marks)

OR

- 4 a. Explain inverting and non-inverting operational amplifiers. (08 Marks)
b. Explain the inverting summing amplifier with neat circuit diagram. Calculate the output voltage of three input inverting summing amplifier having :
 $R_1 = 200\text{K}\Omega$ $R_2 = 250\text{K}\Omega$ $R_3 = 500\text{K}\Omega$ $R_f = 1\text{M}\Omega$,
 $V_1 = -2\text{V}$ $V_2 = -1\text{V}$ and $V_3 = +3\text{V}$. (08 Marks)
c. Draw the base bias circuit using a silicon transistor with $\beta = 50$, $R_B = 100\text{K}\Omega$, $R_C = 1\text{k}\Omega$ and $V_{CC} = 10\text{V}$. Find the values of I_C and V_{CE} . (04 Marks)

Module-3

- 5 a. State and prove the De – Morgan's theorem. (06 Marks)
b. Explain the full adder circuit with truth table. (06 Marks)
c. Convert the following :
 $(49.5)_{10} = (?)_{16}$
 $(1062.403)_8 = (?)_{10}$
 $(642.71)_8 = (?)_2$
 $(734)_{10} = (?)_2$ (08 Marks)

OR

- 6 a. Realize AND, OR and NOT gates using universal gates. (06 Marks)
- b. Simplify the given Boolean equation : $y = (A + \bar{B}) \cdot (CD + E)$ and realize using NAND gates only. (06 Marks)
- c. Perform the subtraction with the following binary numbers using 1's and 2's compliment method.
- i) $(10010)_2 - (10011)_2$
- ii) $(11010)_2 - (10000)_2$ (08 Marks)

Module-4

- 7 a. Explain clocked R-S flip-flop and R-S flip-flop with its logic diagram, logic symbol and truth table. (10 Marks)
- b. Explain the architecture of 8051 microcontroller with block diagram in detail. (10 Marks)

OR

- 8 a. With the help of block diagram, explain the microcontroller based stepper motor control system. (08 Marks)
- b. Explain NAND gate and NOR gate latch with logic diagram and truth table. (08 Marks)
- c. Compare microcontroller and micro processor. (04 Marks)

Module-5

- 9 a. Explain the construction and working of LVDT and its applications. (10 Marks)
- b. Explain elements of communication system with block diagram. (04 Marks)
- c. List the differences between amplitude modulation and frequency modulation. (06 Marks)

OR

- 10 a. Define amplitude modulation. Derive mathematical expression and draw waveforms. (08 Marks)
- b. Explain the piezoelectric transducer and photoelectric transducer. (06 Marks)
- c. Explain the frequency modulation with neat waveforms. (06 Marks)
